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# FDW252P

SEMICONDUCTOR IM

## P-Channel 2.5V Specified PowerTrench<sup>®</sup> MOSFET

### **General Description**

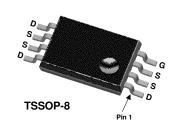
This P-Channel 2.5V specified MOSFET is a rugged gate version of Fairchild Semiconductor's advanced PowerTrench process. It has been optimized for power management applications with a wide range of gate drive voltage (2.5V - 12V).

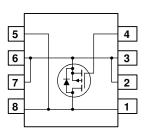
### Applications

- Load switch
- Motor drive
- DC/DC conversion
- Power management

### Features

- $\begin{array}{c} -8.8 \text{ A}, \ -20 \text{ V}. \ \mathsf{R}_{\mathsf{DS}(\mathsf{ON})} = 0.0125 \ \Omega \ \textcircled{O} \ \mathsf{V}_{\mathsf{GS}} = -4.5 \text{ V} \\ \mathsf{R}_{\mathsf{DS}(\mathsf{ON})} = 0.018 \ \Omega \ \textcircled{O} \ \mathsf{V}_{\mathsf{GS}} = -2.5 \text{ V} \end{array}$
- Extended V<sub>GSS</sub> range (±12V) for battery applications
- Low gate charge
- High performance trench technology for extremely
  low R<sub>DS(ON)</sub>
- Low profile TSSOP-8 package





## Absolute Maximum Ratings T<sub>A</sub>=25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V <sub>DSS</sub>	Drain-Source Voltage		-20	V
V <sub>GSS</sub>	Gate-Source Voltage		± 12	V
ID	Drain Current – Continuous	(Note 1)	-8.8	А
	- Pulsed		-50	
PD	Power Dissipation	(Note 1a)	1.3	W
		(Note 1b)	0.6	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperatu	re Range	-55 to +150	°C
Therma	I Characteristics			
R <sub>0JA</sub>	Thermal Resistance, Junction-to-Ambient	(Note 1a)	96	°C/W
		(Note 1b)	208	

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Device Marking	Device	Reel Size	Tape width	Quantity
252P	FDW252P	13"	16mm	2500 units

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Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics					
BV <sub>DSS</sub>	Drain–Source Breakdown Voltage	$V_{GS}$ = 0 V, I <sub>D</sub> = -250 µA	-20			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D$ = –250 µA, Referenced to 25°C		-12		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{\text{DS}} = -16 \text{ V},  V_{\text{GS}} = 0 \text{ V}$			-1	μA
I <sub>GSSF</sub>	Gate–Body Leakage, Forward	$V_{GS} = -12 \text{ V}, \qquad V_{DS} = 0 \text{ V}$			-100	nA
I <sub>GSSR</sub>	Gate–Body Leakage, Reverse	$V_{GS}$ = 12 V, $V_{DS}$ = 0 V			100	nA
On Char	acteristics (Note 2)					
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	-0.6	-0.8	-1.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D$ = –250 µA, Referenced to 25°C		3.5		mV/°C
R <sub>DS(on)</sub>	Static Drain–Source On–Resistance	$ \begin{array}{l} V_{GS} = -4.5 \ V,  I_D = -8.8 \ A \\ V_{GS} = -2.5 \ V,  I_D = -7.2 \ A \\ V_{GS} = -4.5 \ V, \ I_D = -8.8 \ A, \ T_J = 125^\circ C \end{array} $		10 14 13	12.5 18 19	mΩ
I <sub>D(on)</sub>	On–State Drain Current	$V_{GS} = -4.5 V$ , $V_{DS} = -5 V$	-50			А
g <sub>FS</sub>	Forward Transconductance	$V_{DS} = -10 V$ , $I_{D} = -8.8 A$		46		S
Dynamic	Characteristics					
C <sub>iss</sub>	Input Capacitance			5045		pF
Coss	Output Capacitance	$V_{\rm DS} = -10 \text{ V},  V_{\rm GS} = 0 \text{ V},$		1035		pF
C <sub>rss</sub>	Reverse Transfer Capacitance	f = 1.0 MHz		549		pF
Switchin	g Characteristics (Note 2)					
t <sub>d(on)</sub>	Turn–On Delay Time			8	16	ns
tr	Turn–On Rise Time	$V_{DD} = -10 V$ , $I_D = -1 A$ ,		14	25	ns
t <sub>d(off)</sub>	Turn–Off Delay Time	$V_{GS} = -4.5 \text{ V},  R_{GEN} = 6 \Omega$		130	208	ns
t <sub>f</sub>	Turn–Off Fall Time			80	128	ns
Qg	Total Gate Charge			41	66	nC
Q <sub>gs</sub>	Gate–Source Charge	$V_{DS} = -10 \text{ V}, \qquad I_D = -8.8 \text{ A}, V_{GS} = -4.5 \text{ V}$		7		nC
Q <sub>ad</sub>	Gate-Drain Charge	$v_{GS} = -4.5 V$		11		nC

## **Drain–Source Diode Characteristics and Maximum Ratings**

ls	Maximum Continuous Drain-Sourc	e Diode Forward Currer	t		-1.2	А
$V_{\text{SD}}$	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$ , $I_{S} = -1.2$	A (Note 2)	-0.6	-1.2	V

Notes:

 $\mathsf{Q}_{\mathsf{gd}}$ 

1. R<sub>0.1A</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta CA}$  is determined by the user's board design.

a)  $R_{\theta JA}$  is 96°C/W (steady state) when mounted on a 1 inch² copper pad on FR-4. b)  $R_{\theta JA}^{\circ}$  is 208°C/W (steady state) when mounted on a minimum copper pad on FR-4.

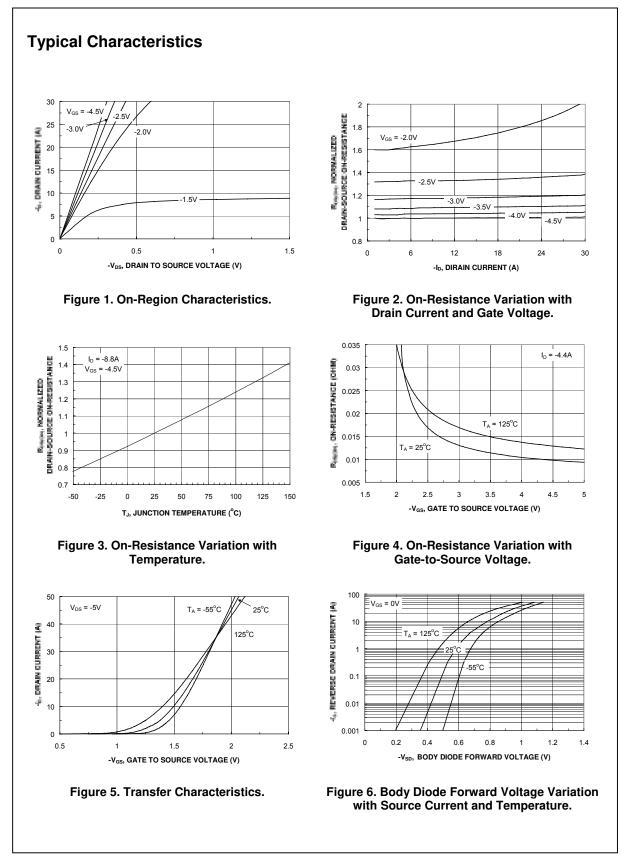
2. Pulse Test: Pulse Width <  $300\mu$ s, Duty Cycle < 2.0%

Gate-Drain Charge

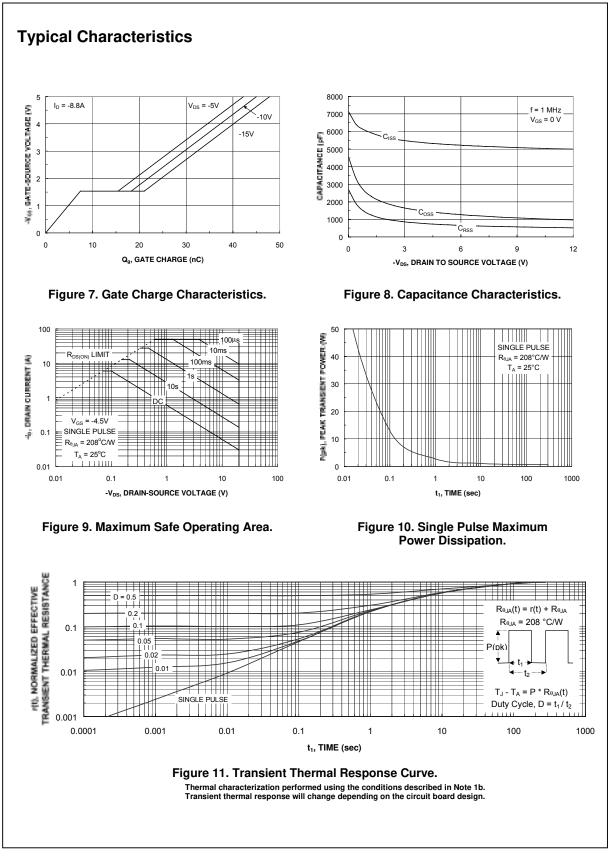
# FDW252P

nC

11



# FDW252P



FDW252P

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